# The RF Line Microwave Pulse Power Transistors

... designed for Class B and C common base amplifier applications in short and long pulse TACAN, IFF, DME, and radar transmitters.

- Guaranteed Performance @ 1090 MHz, 35 Vdc Output Power = 2.0 Watts Peak Minimum Gain = 10 dB
- 100% Tested for Load Mismatch at All Phase Angles with 10:1 VSWR
- Industry Standard Package
- Nitride Passivated
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration
- Internal Input Matching for Broadband Operation
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	20	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Emitter-Base Voltage	VEBO	3.5	Vdc
Collector Current — Continuous	IC	250	mAdc
Total Device Dissipation @ T <sub>C</sub> = 25°C (1) Derate above 25°C	PD	7.0 40	Watts mW/°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

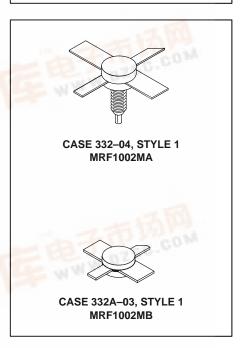
### THERMAL CHARACTERISTICS

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Characteristic	Symbol	Max	Unit	
Thermal Resistance, Junction to Case (2)	R <sub>0</sub> JC	25	°C/W	

# MRF1002MA MRF1002MB

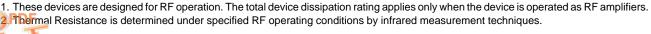
2.0 W (PEAK), 960-1215 MHz MICROWAVE POWER TRANSISTORS NPN SILICON



# **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•		_
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 5.0 mAdc, I <sub>B</sub> = 0)	V(BR)CEO	20		布场	Vdc
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 5.0 mAdc, V <sub>BE</sub> = 0)	V(BR)CES	50	WWW	.07ec.	Vdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = 5.0 mAdc, I <sub>E</sub> = 0)	V(BR)CBO	50	_	_	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 1.0 mAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	3.5	_	_	Vdc
Collector Cutoff Current (VCB = 35 Vdc, IE = 0)	ІСВО	_	_	0.5	mAdc
ON CHARACTERISTICS				•	
DC Current Gain (IC = 100 mAdc, VCE = 5.0 Vdc)	hFE	10	_	100	_

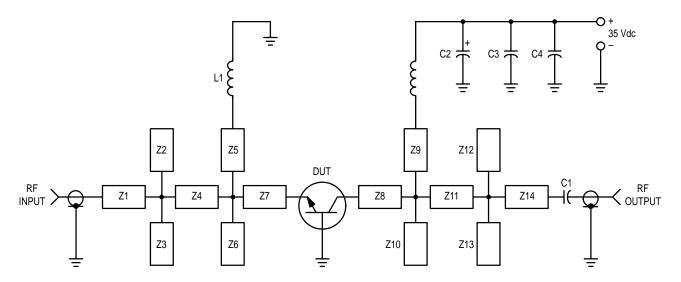
NOTES: (continued)





# **ELECTRICAL CHARACTERISTICS** — **continued** ( $T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS					
Output Capacitance ( $V_{CB} = 35 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	C <sub>ob</sub>	_	2.5	5.0	pF
FUNCTIONAL TESTS (Pulse Width = 10 μs, Duty Cycle = 1.0%)					
Common–Base Amplifier Power Gain (V <sub>CC</sub> = 35 Vdc, P <sub>out</sub> = 2.0 W pk, f = 1090 MHz)	G <sub>PB</sub>	10	12	_	dB
Collector Efficiency (V <sub>CC</sub> = 35 Vdc, P <sub>out</sub> = 2.0 W pk, f = 1090 MHz)	η	40	45	_	dB
Load Mismatch (V <sub>CC</sub> = 35 Vdc, P <sub>out</sub> = 2.0 W, f = 1090 MHz, VSWR = 10:1 All Phase Angles)	Ψ	No Degradation in Power Output			



C1, C3 — 220 pF Chip Capacitor, 100 mil ATC

C2 — 20  $\mu$ F/50 Vdc Electrolytic C4 — 0.1  $\mu$ F Erie Redcap

L1, L2 — 2 Turns #18 AWG, 1/8" ID

Z1–Z14 — Distributed Microstrip Elements, See Photomaster

Board Material — 0.031" Thick Teflon-Fiberglass,  $\varepsilon_r = 2.56$ 

Figure 1. 1090 MHz Test Circuit

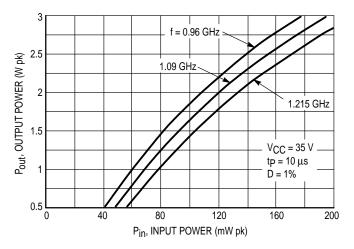


Figure 2. Output Power versus Input Power

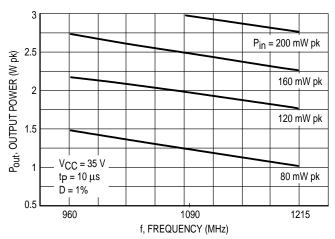


Figure 3. Output Power versus Frequency

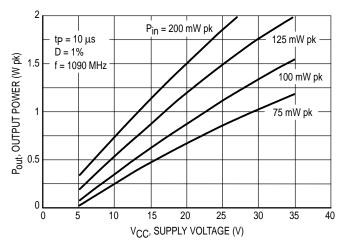


Figure 4. Output Power versus Supply Voltage

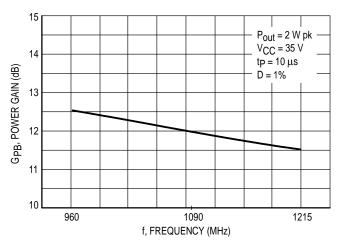
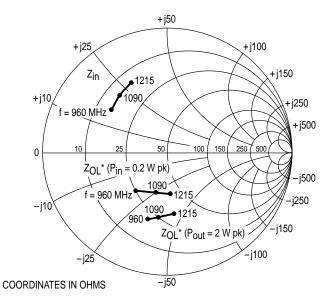


Figure 5. Power Gain versus Frequency



 $V_{CC} = 35 \text{ Vdc},$  $t_{P} = 10 \mu \text{s}, D = 1.0\%$ 

f MHz	Z <sub>in</sub> Ohms	$Z_{OL}^*$ Ohms $P_{Out} = 2.0 \text{ W pk}$	Z <sub>OL</sub> * Ohms P <sub>in</sub> = 0.2 W pk
960	15.5 + j16.5	20 + j32.5	25 + j21
1090	15 + j20	25 + j34	31 + j26
1215	14 + j27	33.5 + j42.5	37 + j32.5

Z<sub>OL</sub>\* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage, and frequency.

Figure 6. Series Equivalent Input/Output Impedance

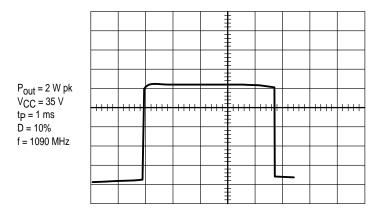
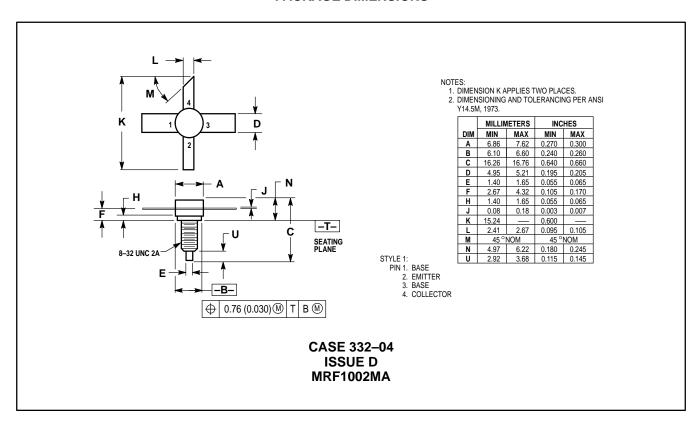
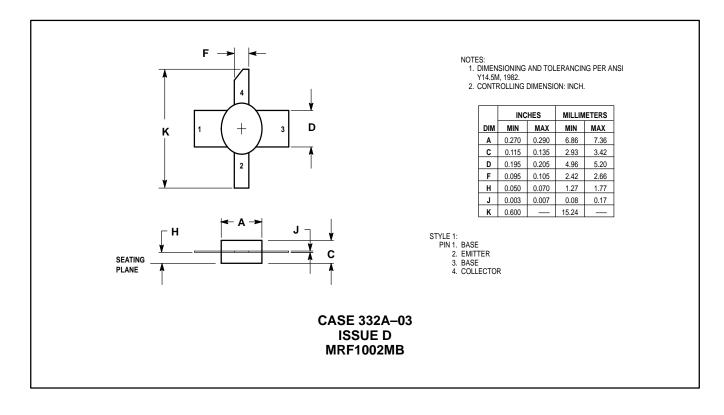


Figure 7. Typical Long Pulse Performance

## **PACKAGE DIMENSIONS**





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